

# 2SK1515, 2SK1516

Silicon N Channel MOS FET

REJ03G0946-0200 (Previous: ADE-208-1286) Rev.2.00 Sep 07, 2005

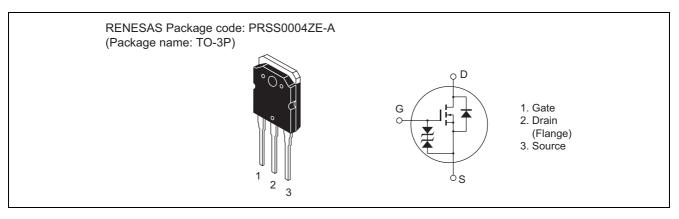
## Application

High speed power switching

### Features

- Low on-resistance
- High speed switching
- Low drive current
- Built-in fast recovery diode ( $t_{rr} = 120 \text{ ns}$ )
- Suitable for motor control, switching regulator, DC-DC converter

### Outline





# Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Drain to source voltage	2SK1515	V <sub>DSS</sub>	450	V
	2SK1516		500	
Gate to source voltage		V <sub>GSS</sub>	±30	V
Drain current		ID	10	А
Drain peak current		I <sub>D(pulse)</sub> * <sup>1</sup>	30	А
Body to drain diode reverse drain current		I <sub>DR</sub>	10	А
Channel dissipation		Pch* <sup>2</sup>	100	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C
Channel temperature		Tch	150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at  $T_C = 25^{\circ}C$ 

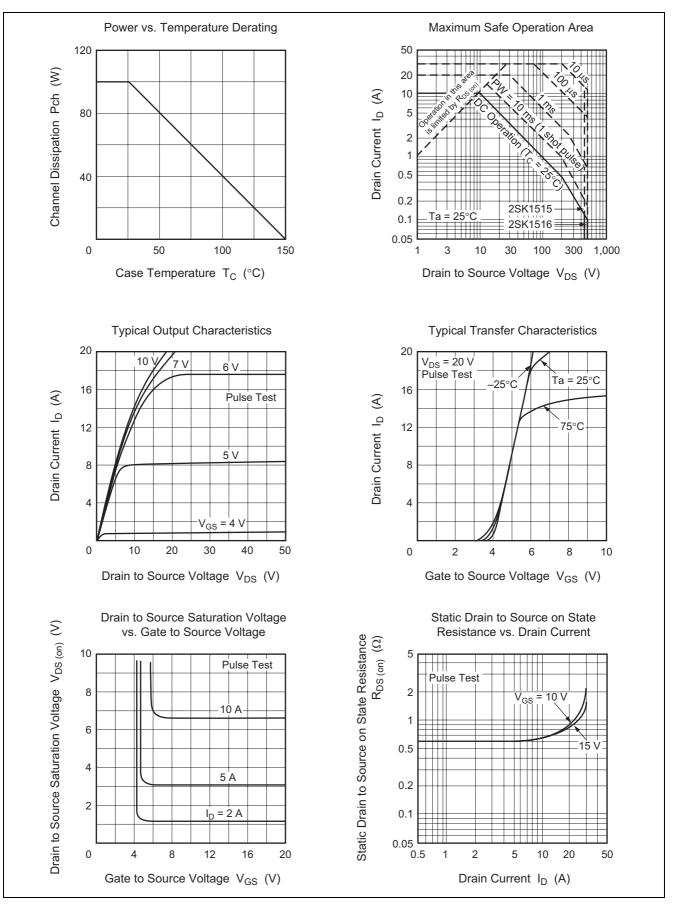
# **Electrical Characteristics**

							$(Ta = 25^{\circ}C)$
ltem		Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source	2SK1515	V <sub>(BR)DSS</sub>	450	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
breakdown voltage	2SK1516		500				
Gate to source breakdown voltage		V <sub>(BR)GSS</sub>	±30	—	—	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current		I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, \text{ V}_{DS} = 0$
Zero gate voltage drain	2SK1515	I <sub>DSS</sub>	—	—	250	μA	$V_{DS} = 360 \text{ V}, \text{ V}_{GS} = 0$
	2SK1516						$V_{DS} = 400 V, V_{GS} = 0$
Gate to source cutoff voltage		V <sub>GS(off)</sub>	2.0	_	3.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on	2SK1515	R <sub>DS(on)</sub>	_	0.6	0.8	Ω	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}^{*3}$
state resistance	2SK1516		_	0.7	0.9		
Forward transfer admittance		y <sub>fs</sub>	4.0	7.0	_	S	$I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$
Input capacitance		Ciss	_	1100	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$
Output capacitance		Coss		310	_	pF	f = 1 MHz
Reverse transfer capacitance		Crss	_	50	—	pF	
Turn-on delay time		t <sub>d(on)</sub>	_	15	—	ns	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V},$
Rise time		tr	_	65		ns	$R_L = 6 \Omega$
Turn-off delay time		t <sub>d(off)</sub>	_	95		ns	
Fall time		t <sub>f</sub>	_	55		ns	
Body to drain diode forward voltage		V <sub>DF</sub>	_	1.0	—	V	$I_F = 10 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time		t <sub>rr</sub>	—	120	—	ns	$I_F = 10 \text{ A}, V_{GS} = 0,$ $di_F/dt = 100 \text{ A}/\mu \text{s}$

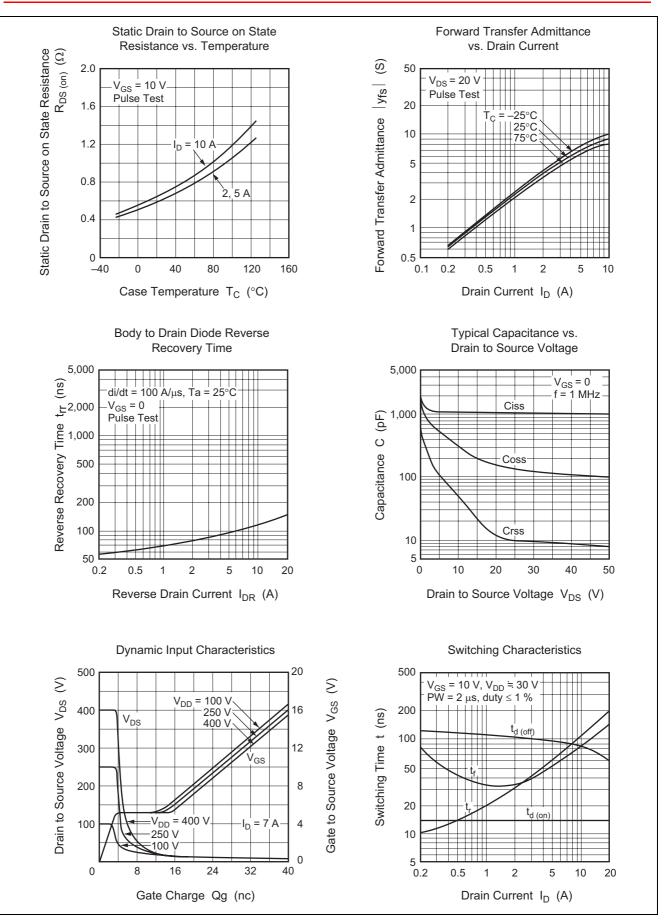
Note: 3. Pulse test



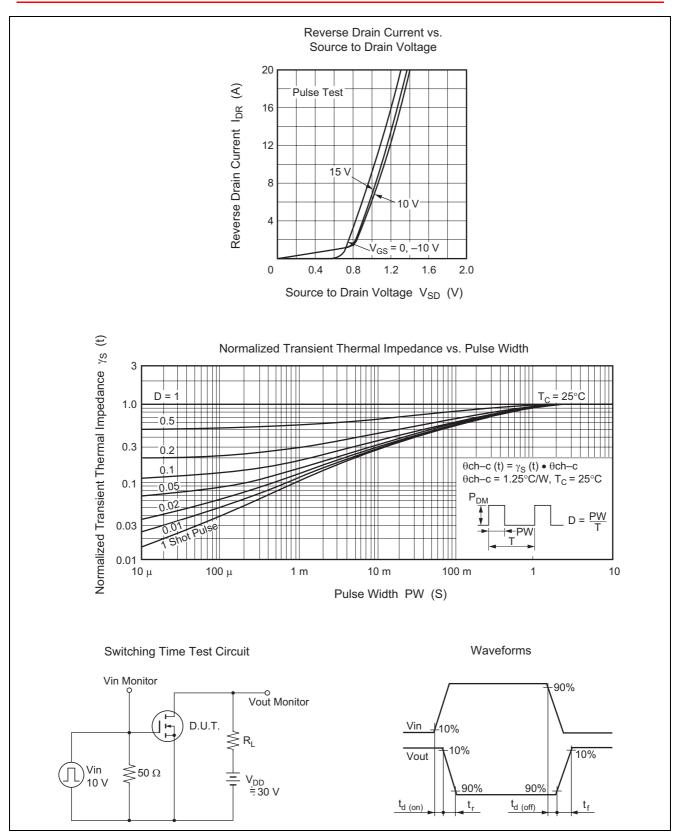
### **Main Characteristics**



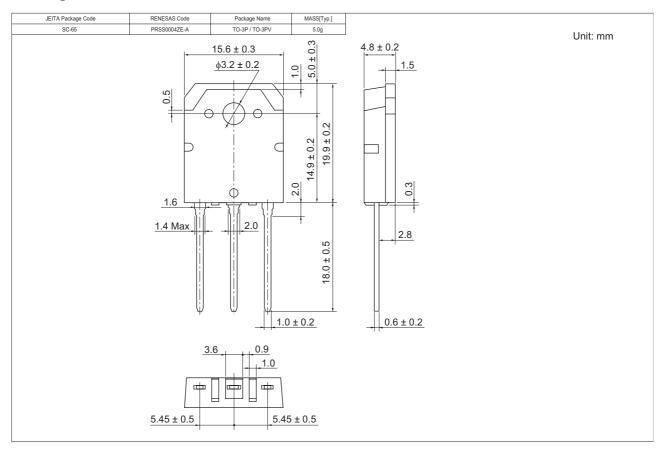








### **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SK1515-E	360 pcs	Box (Tube)
2SK1516-E	360 pcs	Box (Tube)

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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